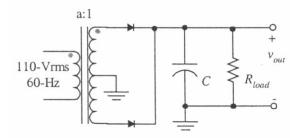
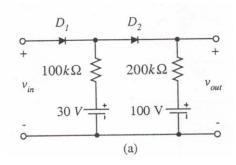
Show all work. Clearly indicate final answer(s).

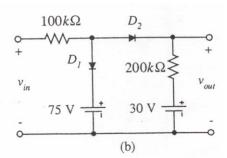
- 1. (20 points) A particular diode has a reverse saturation current of $0.2\mu A$, n=1.6, and V_T =26mV. Determine the diode current when the voltage across the diode is 0.4V. Also determine the forward resistance of the diode at this operating point. Hint: Assume zero contact resistance.
- 2. (40 points) Determine the capacitor size for the circuit shown to the right when a=6 and R_{load} =100 Ω . The minimum voltage to the load must not drop by more than 20%. Consider the diodes and transformer ideal.



3. (40 points)

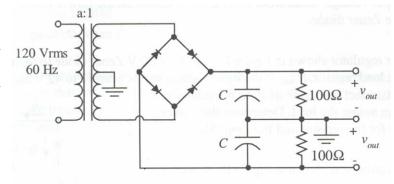
- a. The input voltage to the clipper circuit in figure (a) varies linearly from 0 to 150V. Sketch the output voltage, vout, on the same time plot as the input. Assume the diodes are ideal.
- b. Repeat part (a) for the circuit in figure (b).





EXTRA CREDIT (20 points max):

An integrated circuit requires plus and minus voltages for their operation. Using the circuit to the right, determine the transformer winding ratio and the capacitor size needed to get a maximum of 14V and a minimum of 12V at the output when the input is 120Vrms 60Hz, V_{ON} =0.7V for each of the diodes and R_f =0. Ignore transformer loss.



(HOPEFULLY!) USEFUL STUFF

$$v_{out,avg} = \frac{1}{T} \int_{0}^{T} v_{out}(t) dt = \frac{1}{T} \int_{0}^{T/2} V_{0} \sin \frac{2\pi t}{T} dt + \frac{1}{T} \int_{T/2}^{T} 0 dt = \frac{V_{0}}{\pi} + 0 \approx 0.318 V_{0}$$

$$R_i = \frac{V_{s \min} - V_z}{I_{L \max} + I_{z \min}} = \frac{V_{s \max} - V_z}{I_{L \min} + I_{z \max}}$$

 $k_T = -2.0 \text{ mV/}^{\circ}\text{C}$ for Si, $-2.5 \text{ mV/}^{\circ}\text{C}$ for Ge

$$i_D = I_O(e^{\frac{v_D}{nV_T}} - 1)$$

26mV@room temperature

$$\% reg = \frac{V_{out \max} - V_{out \min}}{V_{out no \min al}} *100$$

$$r_d = \frac{nV_T}{i_D}$$

$$C = \frac{V_{\text{max}}}{\Delta V f_p R_L}$$

$$C_F = \frac{V_{s \max} - V_Z}{\Delta V f_n R_i}$$

$$V_{\scriptscriptstyle ON}\left(T_{\scriptscriptstyle New}\right) - V_{\scriptscriptstyle ON}\left(T_{\scriptscriptstyle room}\right) = k_{\scriptscriptstyle T}\left(T_{\scriptscriptstyle New} - T_{\scriptscriptstyle room}\right)$$

$$J = q(p\mu_p + n\mu_n)E$$

$$I_0(atT_2) = I_0(atT_1)e^{k_i(T_2 - T_1)}$$

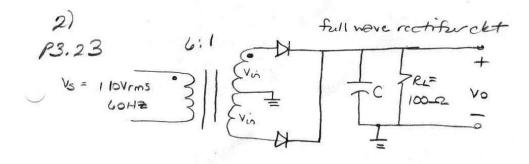
$$R = \frac{\rho L}{A} = \frac{L}{\sigma A}$$

$$I_{z \max} = \frac{I_{L \min}(V_z - V_{s \min}) + I_{L \max}(V_{s \max} - V_z)}{V_{s \min} - 0.9V_z - 0.1V_{s \max}}$$

$$i_{D} = I_{0} \left(e^{\frac{V_{0}}{NV_{T}}} \right) = (2x10^{7})e^{\frac{(0.4)}{(1.c)(0.026)}} - 1$$

$$i_{D} = 3mA$$

$$R_{f} = r_{d} = \frac{nV_{f}}{iD} = \frac{(1.6)(26m)}{3m} = \frac{13.9 \Omega}{2}$$



Given: Ideal diode (Von=0, Rf=0, Rr=00)

Ideal transformer

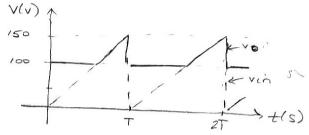
Vinmin > 0.8 Vinnex (can't dropby more than 20%)

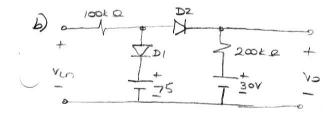
Vspeek = 110-12 = 155.6 Vpick 5 Vinperk = 155.6 = 13 Vpeck (6)(2) 2 center top

Vinmin = (0.8)(13) = 10.4V (not a necessary calculationcould use av= Vmax-Vmin=2.6V)

3) ideal diodes & Von=0, Rf=0, Rr=00

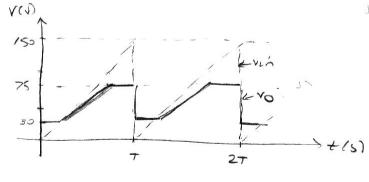
SVIN <30V Dioff, D20ff, Vo=100V S30 \(\text{Vin} \(\text{100V} \) Dion, D20ff, Vo=100V SVIN \(\text{100V}, Dion, D2 on, Vo=Vin (everything is in parallel if diodes are ideal)





Vin < 30 V, D, off, D20ff, Vo=30V 30 < Vin < 75, D10ff, D2 on Vo= 30 + (Vin-30)(200/c) Vo= 10 + 2 Vin

max vo=75V (when D, on) vo=75@ 75=10+3vin Vin=3(75-10=97.51)



Vin	o V
<30	30
50	43,3
75	40
>97.51	75
- 1	
- 1	

ECP325

rolting needed a secondary:

12012 = 169.7V

$$C = \frac{V_{mex}}{\Delta V + \rho R_L} = \frac{14}{2(12000)} = 583 \text{ m/F}$$